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Advanced European Infrastructures for Detectors at Accelerators

Milestone Report

Simulation tutorial on HV/HR-CMOS TCAD and Geant4 simulations

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MILESTONE REPORT

SIMULATION TUTORIAL ON HV/HR-CMOS TCAD AND GEANT4 SIMULATIONS

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Abstract:

A simulation workshop and a simulation tutorial were organized by WP6 (Novel high voltage and resistive CMOS sensors) in Marseille on 12-13 May 2016 (MS7 and MS48), focused on devices (TCAD) and detector systems (Geant 4).

AIDA-2020 Consortium, 2017



AIDA-2020 Consortium, 2017

For more information on AIDA-2020, its partners and contributors please see www.cern.ch/AIDA2020

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TABLE OF CONTENTS

1. W	ORKSHOP SUMMARY	. 4
1.1	Objectives	4
1.2	DETAILS ABOUT THE MEETING	4
1.3	LIST OF PARTICIPANTS	5

1. WORKSHOP SUMMARY

1.1 OBJECTIVES

AIDA

TCAD and Geant4 simulations are important tools widely used in the design of CMOS sensors. It is therefore critical that scientists, involved in sensor design, get familiar with simulation tools as soon as possible. Therefore, we decided to organize the Simulation Tutorial in month 13 rather than in month 24. The shift allowed us to merge two similar events: the Simulation Workshop and the Simulation Tutorial. This change brought several advantages. First of fall, researchers became familiar with the simulation tools before starting their work on large designs. The change also allowed the participation of a larger audience. Finally, by merging the two events significant costs savings were achieved for the organization of the events and travel expenses.

Lecturers for the Simulation Tutorial were Fares Djama (University of Marseille), Jian Liu (CPPM), Mathieu Benoit (UNIGE) and Patrick Pangaud (CPPM). The University of Bonn (Tomasz Hemperek) prepared the simulation infrastructure and the material used for the tutorials.

The simulation tutorial included two sets of lectures:

- Fares Djama (University of Marseille) "Simulation of silicon detector with GEANT-4 (part1/2)"
- Jian Liu (CPPM), Mathieu Benoit (UNIGE) and Patrick Pangaud (CPPM); "Hands on TCAD simulation (part1/2)"

The timetable of the event is available at <u>https://indico.cern.ch/event/497449/timetable/</u>

Type of activity	Thematic Workshop
Title	WP6 Simulations Tutorial
Date	12-13 May 2016
Place	Marseille (FR)
Type of audience	Scientific community, ESRs
Size of audience	25
Scope of the workshop	International
Link	https://indico.cern.ch/event/497449/

1.2 DETAILS ABOUT THE MEETING

SIMULATION TUTORIAL ON HV/HR-CMOS TCAD AND GEANT4 SIMULATIONS

1.3 LIST OF PARTICIPANTS

Fabrice	Balli	CEA/IRFU, Centre d'etude de Saclay Gif-sur-Yvette (FR)
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Mathieu	Benoit	UNIGE
Patrick	Breugnon	CPPM/CNRS/AMU
Matthew	Buckland	University of Liverpool (GB)
Alessandro	Calandri	CPPM, Aix-Marseille Université, CNRS/IN2P3 (FR)
Francesco Armando	Di Bello	Universite de Geneve (CH)
Fares	Djama	CNRS/IN2P3 CPPM - Aix-Marseille Univ.
Stephanie	Godiot	Centre National de la Recherche Scientifique (FR)
Tomasz	Hemperek	Universitaet Bonn (DE)
Kestutis	Kanisauskas	University of Glasgow (GB)
Mohamed	Lachkar	CEA/IRFU/SPP
Jian	Liu	СРРМ
Igor	Mandic	Jozef Stefan Institute (SI)
Cesar	Marin	CERN
Lingxin	Meng	University of Liverpool/Universite de Geneve
Mohsine	Menouni	Centre National de la Recherche Scientifique (FR)
Patrick	Pangaud	CPPM/CNRS/AMU
Ivan	Peric	KIT
Christian	Riegel	Bergische Universitaet Wuppertal (DE)
Alexandre	Rozanov	CPPM, Aix-Marseille Université, CNRS/IN2P3 (FR)
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